

Standard Recovery Diodes, Generation 2 DO-5 (Stud Version), 50 A



PRODUCT SUMMARY			
I _{F(AV)} 50 A			
Package	DO-203AB (DO-5)		
Circuit configuration	Single diode		

FEATURES

• High surge current capability





- · Stud cathode and stud anode version
- Wire version available
- Low thermal resistance
- Designed and qualified for multiple level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

- · Battery charges
- Converters
- Power supplies
- · Machine tool controls
- Welding

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
		50	Α		
I _{F(AV)}	T _C	140	°C		
I _{F(RMS)}		78	Α		
I _{FSM}	50 Hz	800	٨		
	60 Hz	830	Α		
l ² t	50 Hz	3200	A ² s		
	60 Hz	2900	A-5		
V _{RRM}	Range	400 to 1200	V		
T _J		-55 to +180	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA	
40		400	500		
VS-50PF(R)(W)	80	800	960	9	
	120	1200	1440		



FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current		180° conduction, half sine wave		half sing ways	50	А
at case temperature	I _{F(AV)}	160 Conduc	ction, nan sine w	ave	140	°C
Maximum RMS forward current	I _{F(RMS)}				78	Α
		t = 10 ms	No voltage	Sinusoidal half wave, initial T _J = 150 °C	800	А
Maximum peak, one-cycle forward,	I _{FSM}	t = 8.3 ms	reapplied		830	
non-repetitive surge current		t = 10 ms	100 % V _{RRM} reapplied		670	
		t = 8.3 ms			700	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage reapplied		3200	A ² s
		t = 8.3 ms			2900	
		t = 10 ms	100 % V _{RRM} reapplied		2260	
		t = 8.3 ms			2050	
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied		32 000	A²√s	
Low level value of threshold voltage	V _{F(TO)}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum		0.77	V	
Low level value of forward slope resistance	r _f	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		4.30	mΩ	
Maximum forward voltage drop	V_{FM}	I_{pk} = 125 A, T_J = 25 °C, t_p = 400 μ s rectangular wave		1.40	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-55 to +180	°C	
Maximum thermal resistance, junction to case	R _{thJC}	R _{thJC} DC operation		IZ AA I	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25	K/W	
Allowable mounting torque		Tighting on nut ⁽¹⁾ Not lubricated threads	3.4 ^{+ 0 - 10} % (30)	N · m	
		Tighting on Hexagon ⁽²⁾ Lubricated threads	2.3 ^{+ 0 - 10} % (20)	(lbf·in)	
Approximate weight			15.8	g	
Approximate weight			0.56	oz.	
Case style		See dimensions - link at the end of datasheet DO-203AB (DO-		AB (DO-5)	

Notes

⁽²⁾ Torque must be applicable only to Hexagon and not to plastic structure

△R _{th} JC CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.11	0.10				
120°	0.16	0.16				
90°	0.20	0.22	$T_J = T_J$ maximum	K/W		
60°	0.29	0.31				
30°	0.49	0.50				

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

⁽¹⁾ As general recommendation we suggest to tight on Hexagon and not on nut



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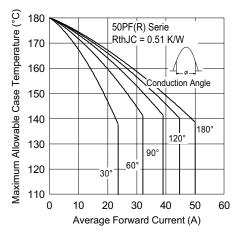


Fig. 1 - Current Ratings Characteristics

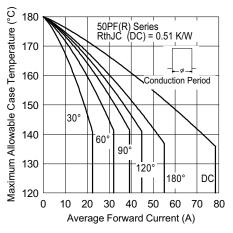


Fig. 2 - Current Ratings Characteristics

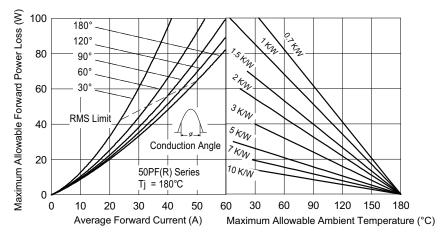


Fig. 3 - Forward Power Loss Characteristics

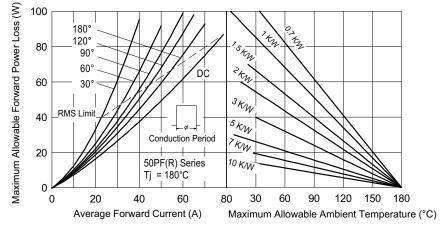


Fig. 4 - Forward Power Loss Characteristics

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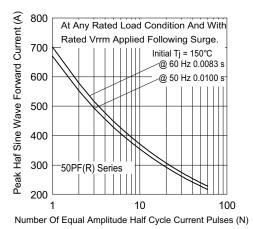


Fig. 5 - Maximum Non-Repetitive Surge Current

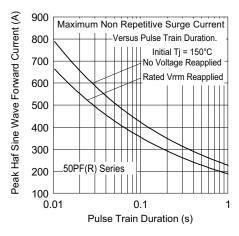


Fig. 6 - Maximum Non-Repetitive Surge Current

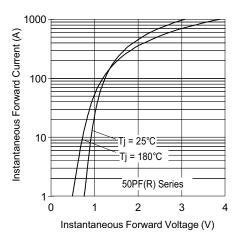


Fig. 7 - Forward Voltage Drop Characteristics

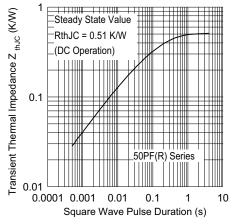
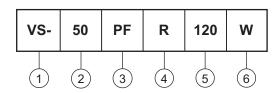


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - • 50 = Standard device

 52 = Isolated lead on standard terminal with silicone sleeve available for 1200 V only (red = Reverse polarity)
 (blue = Normal polarity)

3 - PF = Plastic package

None = Stud normal polarity (cathode to stud)

• R = Stud reverse polarity (anode to stud)

Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

None = Standard terminal
 (see dimensions for 50PF(R)... - link at the end of datasheet)

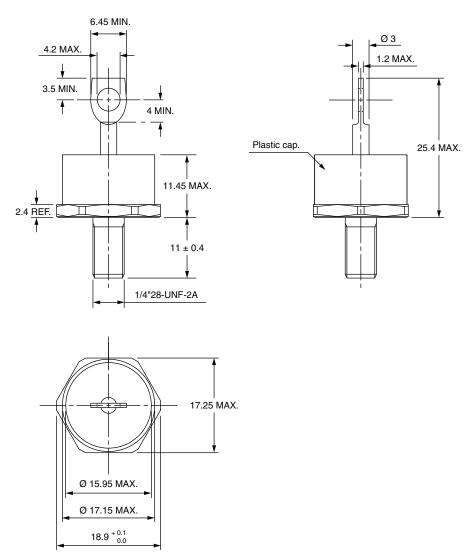
 W = Wire terminal (see dimensions for 50PF(R)...W - link at the end of datasheet)

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95345		



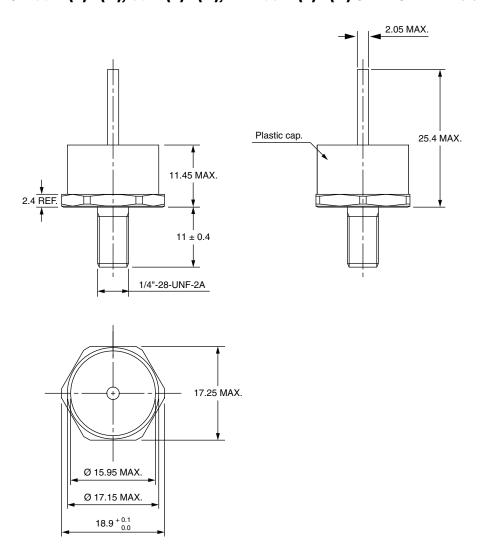
DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W), and 95PF(R)...(W) Series

DIMENSIONS FOR 80PF(R), 50PF(R), AND 95PF(R) SERIES in millimeters



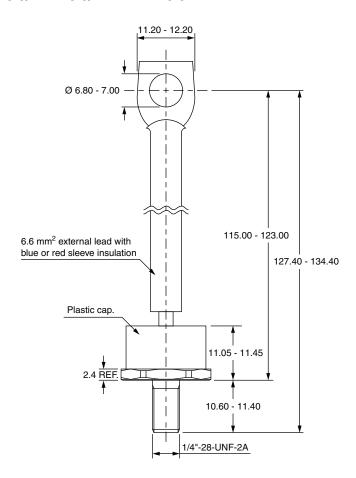


DIMENSIONS FOR 80PF(R)...(W), 50PF(R)...(W), AND 95PF(R)...(W) SERIES in millimeters





DIMENSIONS FOR 52PF(R), 82PF(R), AND 97PF(R) SERIES in millimeters





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